IS27LV020

262,144 x 8 LOW VOLTAGE CMOS EPROM

FEATURES

- Single 2.7V to 3.6V power supply
- Fast access time: 90 ns
- JEDEC-approved pinout
- Low power consumption
  — 20 μA (max) CMOS standby current
  — 10 mA (max) active current at 5 MHz
- High-speed programming
  — Typically less than 16 seconds
- Industrial and commercial temperature ranges available
- Standard 32-pin DIP, PLCC and TSOP packages

DESCRIPTION

The *ISSI* IS27LV020 is a low voltage, low power, high-speed 1 megabit (256K-word by 8-bit) CMOS Programmable Read-Only Memory. It utilizes the standard JEDEC pinout making it funtionally compatible with the IS27C020 EPROM. The IS27LV020 operates from a 2.7V to 3.6V power supply.

The superior access time combined with low power consumption is the result of innovative design and process technology. Maximum power consumption in standby mode is 72 μW. If the device is constantly accessed at 5 MHz, then the maximum power consumption is increased to 36 mW. These power ratings are significantly lower than the standard IS27C020 EPROM.

The IS27LV020 uses *ISSI*'s write programming algorithm which allows the entire chip to be programmed in typically less than 30 seconds.

This product is available in One-Time Programmble (OTP) PDIP, PLCC, and TSOP packages over commercial and industrial temperature ranges.
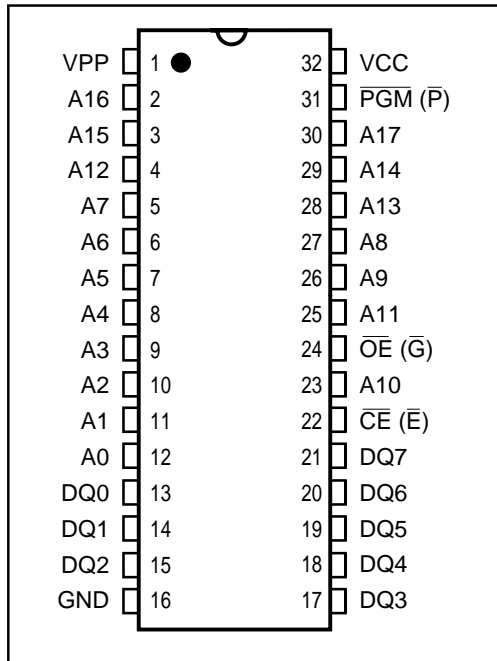
FUNCTIONAL BLOCK DIAGRAM
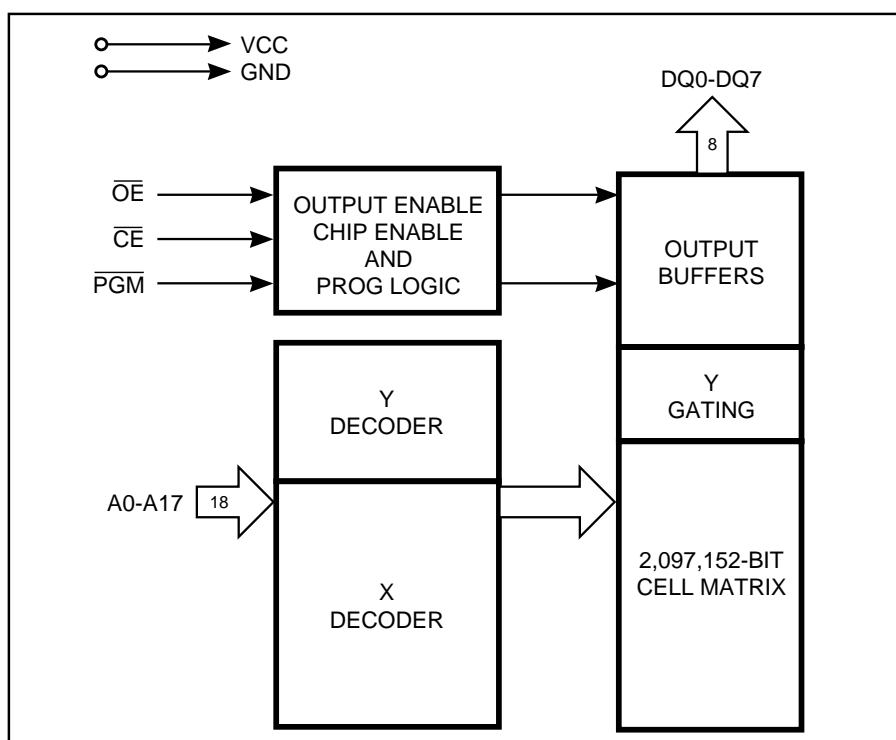
PIN CONFIGURATIONS
32-Pin DIP

PIN DESCRIPTIONS

A0-A17	Address Inputs
$\overline{CE}$ ($\overline{E}$)	Chip Enable Input
DQ0-DQ7	Data Inputs/Outputs
$\overline{OE}$ ($\overline{G}$)	Output Enable Input
$\overline{PGM}$ ($\overline{P}$)	Program Enable Input
Vcc	Power Supply Voltage
VPP	Program Supply Voltage
GND	Ground
NC	No Internal Connection

32-Pin PLCC
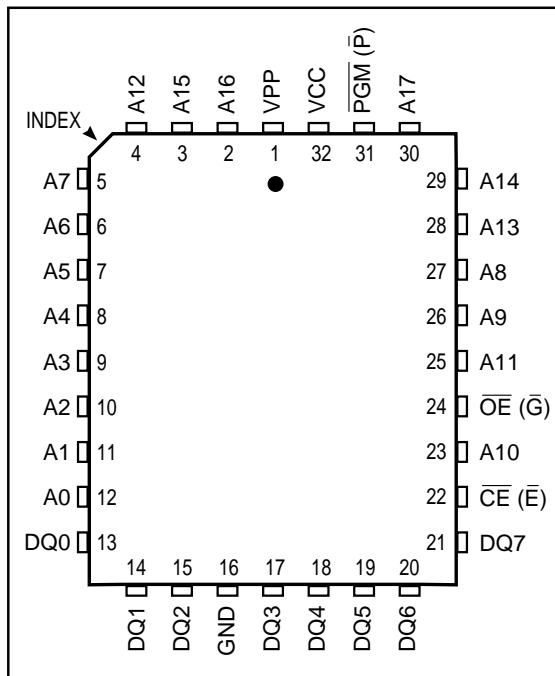
32-Pin TSOP
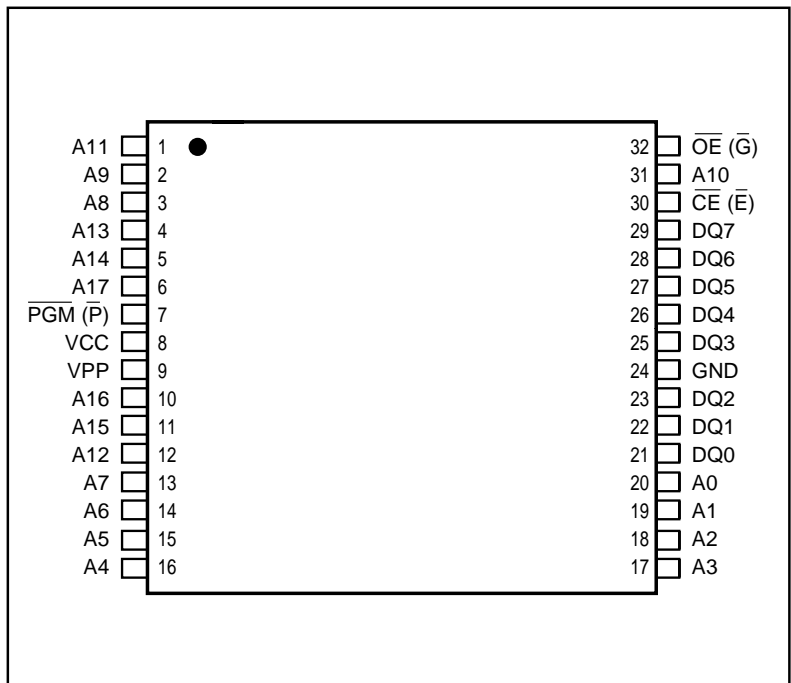
FUNCTIONAL DESCRIPTION

Programming the IS27LV020

Upon delivery, the IS27LV020 has 2,097,152 bits in the "ONE", or HIGH state. "ZEROs" are loaded into the IS27LV020 through the procedure of programming.

The programming mode is entered when $12.5V \pm 0.25V$ is applied to the V_{PP} pin, $V_{CC} = 6V$, $\overline{CE}$ and $\overline{PGM}$ is at V_{IL}, and $\overline{OE}$ is at V_{IH}. For programming, the data to be programmed is applied eight bits in parallel to the data output pins.

The write programming algorithm reduces programming time by using 100 μs programming pulses followed by a byte verification to determine whether the byte has been successfully programmed. If the data does not verify, an additional pulse is applied for a maximum of 25 pulses. This process is repeated while sequencing through each address of the EPROM.

The write programming algorithm programs and verifies at $V_{CC} = 6V$ and $V_{PP} = 12.5V$. After the final address is completed, all byte are compared to the original data with $V_{CC} = 5.25V$.

Program Inhibit

Programming of multiple IS27LV020s in parallel with different data is also easily accomplished. Except for $\overline{CE}$, all like inputs of the parallel IS27LV020 may be common. A TTL low-level program pulse applied to an IS27LV020 $\overline{CE}$ input with $V_{PP} = 12.5V \pm 0.25V$, PGM LOW and $\overline{OE}$ HIGH will program that IS27LV020. A high-level $\overline{CE}$ input inhibits the other IS27LV020 from being programmed.

Program Verify

A verify should be performed on the programmed bits to determine that they were correctly programmed. The verify should be performed with $\overline{OE}$ and $\overline{CE}$ at V_{IL}, $\overline{PGM}$ at V_{IH}, and V_{PP} between 12.25V and 12.75V.

Auto Select Mode

The auto select mode allows the reading out of a binary code from an EPROM that will identify its manufacturer and type. This mode is intended for use by programming equipment for the purpose of automatically matching the device to be programmed with its corresponding programming algorithm. This mode is functional in the $25°C \pm 5°C$ ambient temperature range that is required when programming the IS27LV020.

To activate this mode, the programming equipment must force $12.0V \pm 0.5V$ on address line A9 of the IS27LV020.

Two identifier bytes may then be sequenced from the device outputs by toggling address line A0 from V_{IL} to V_{IH}. All other address lines must be held at V_{IL} during auto select mode.

Byte 0 (A0 = V_{IL}) represents the manufacturer code, and byte 1 (A0 = V_{IH}), the device identifier code. For the IS27LV020, these two identifier bytes are given in the Mode Select table. All identifiers manufacturer and device codes will possess odd parity, with the MSB (DQ7) defined as the parity bit.

Read Mode

The IS27LV020 has two control functions, both of which must be logically satisfied in order to obtain data at the outputs. Chip Enable ($\overline{CE}$) is the power control and should be used for device selection. Assuming that addresses are stable, address access time (t_{ACC}) is equal to the delay from $\overline{CE}$ to output (t_{CE}). Output Enable ($\overline{OE}$) is the output control and should be used to get data to the output pins, independent of device selection. Data is available at the outputs t_{OE} after the falling edge of $\overline{OE}$ assuming that $\overline{CE}$ has been LOW and addresses have been stable for at least $t_{ACC} - t_{OE}$.

Standby Mode

The IS27LV020 has a standby mode which reduces the maximum V_{CC} active current. It is placed in standby mode when $\overline{CE}$ is at $V_{CC} \pm 0.3V$. The amount of current drawn in standby mode depends on the frequency and the number of address pins switching. The IS27LV020 is specified with 50% of the address lines toggling at 5 MHz. A reduction of the frequency or quantity of address lines toggling will significantly reduce the actual standby current.

Output OR-Tieing

To accommodate multiple memory connections, a two-line control function is provided to allow for:

1. Low memory power dissipation, and
2. Assurance that output bus contention will not occur.

It is recommended that $\overline{CE}$ be decoded and used as the primary device-selecting function, while $\overline{OE}$ be made a common connection to all devices in the array and connected to the READ line from the system control bus. This assures that all deselected memory devices are in their low-power standby mode and that the output pins are only active when data is desired from a particular memory device.

System Applications

During the switch between active and standby conditions, transient current peaks are produced on the rising and falling edges of Chip Enable. The magnitude of these transient current peaks is dependent on the output capacitance loading of the device at a minimum, a 0.1 μF ceramic capacitor (high-frequency, low inherent inductance) should be used on each device between V_{CC} and GND to minimize transient effects. In addition, to overcome the voltage drop caused by the inductive effects of the printed circuit board traces on EPROM arrays, a 4.7 μF bulk electrolytic capacitor should be used between V_{CC} and GND for each eight devices. The location of the capacitor should be close to where the power supply is connected to the array.

TRUTH TABLE[1,2]

Mode		$\overline{CE}$	$\overline{OE}$	$\overline{PGM}$	A0	A9	V_{PP}	Outputs
Read		V_{IL}	V_{IL}	X	X	X	V_{CC}	D_{OUT}
Output Disable		V_{IL}	V_{IH}	X	X	X	V_{CC}	Hi-Z
Standby		V_{IH}	X	X	X	X	V_{CC}	Hi-Z
Program		V_{IL}	V_{IH}	V_{IL}	X	X	V_{PP}	D_{IN}
Program Verify		V_{IL}	V_{IL}	V_{IH}	X	X	V_{PP}	D_{OUT}
Program Inhibit		V_{IH}	X	X	X	X	V_{PP}	Hi-Z
Auto Select[3,5]	Manufacturer Code	V_{IL}	V_{IL}	X	V_{IL}	V_H	V_{CC}	D5H
	Device Code	V_{IL}	V_{IL}	X	V_{IH}	V_H	V_{CC}	0EH

Notes:
1. $V_H = 12.0V \pm 0.5V$.
2. X = Either V_{IH} or V_{IL}.
3. A1-A8 = A10-A17 = V_{IL}.
4. See DC Programming Characteristics for V_{PP} voltage during programming.
5. The IS27LV020 can use the same write algorithm during program as other IS27C020 or IS27020 devices.

LOGIC SYMBOL
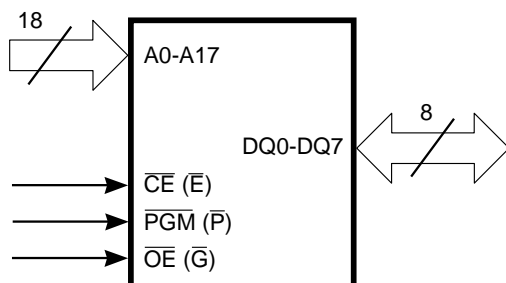
ABSOLUTE MAXIMUM RATINGS[1]

Symbol	Parameter	Value	Unit
V_{TERM}	Terminal Voltage with Respect to GND		
	All pins except A9 and V_{PP}	−0.6 to V_{CC} + 0.5[2]	V
	V_{PP}	V_{CC} − 0.3 to 13.5[2,3]	V
	A9	−0.6 to 13.5[2,3]	V
	V_{CC}	−0.6 to 7.0[2]	V
T_A	Ambient Temperature with Power Applied	−65 to +125	°C
T_{STG}	Storage Temperature (OTP)	−65 to +125	°C
T_{STG}	Storage Temperature (All others)	−65 to +150	°C

Notes:
1. Stress greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Minimum DC input voltage is −0.5V. During transitions, inputs may undershoot to −2.0V for periods less than 10 ns. Maximum DC voltage on output pins is V_{CC} + 0.5V which may overshoot to V_{CC} + 2.0V for periods less than 10 ns.
3. Maximum DC voltage on A9 or V_{PP} may overshoot to +13.5V for periods less than 10 ns.

OPERATING RANGE

Range	Ambient Temperature	V_{CC}
Commercial	0°C to +70°C	2.7 – 3.6V
Industrial[1]	−40°C to +85°C	2.7 – 3.6V

Note:
1. Operating ranges define those limits between which the functionally of the device is guaranteed.

DC ELECTRICAL CHARACTERISTICS[1,2,3] (Over Operating Range)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC} = Min., I_{OH} = −400 µA	2.4	—	V
V_{OL}	Output LOW Voltage	V_{CC} = Min., I_{OL} = 2.0 mA	—	0.4	V
V_{IH}	Input HIGH Voltage[4]		2.0	V_{CC} + 0.5	V
V_{IL}	Input LOW Voltage[4]		−0.3	0.8	V
I_{LI}	Input Load Current	V_{IN} = 0V to +V_{CC}	—	5	µA
I_{LO}	Output Leakage Current	V_{OUT} = 0V to +V_{CC}	—	5	µA

Notes:
1. V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP}. Never try to force V_{PP} LOW to 1V below V_{CC}. Manufacturer suggests to tie V_{PP} and V_{CC} together during the READ operation.
2. **Caution:** the IS27LV020 must not be removed from (or inserted into) a socket when V_{CC} or V_{PP} is applied.
3. Minimum DC input voltage is −0.5V. During transitions, the inputs may undershoot to −2.0V for periods less than 10 ns. Maximum DC voltage on output pins is V_{CC} + 0.5V which may overshoot to V_{CC} + 2.0V for periods less than 10 ns.
4. Tested under static DC conditions.

POWER SUPPLY CHARACTERISTICS[1,2,5] (Over Operating Range)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
I_{CC1}	Vcc Operating Supply Current[3]	Vcc = Max., $\overline{CE}$ = V_{IL} I_{OUT} = 0 mA, f = 5 MHz (Open outputs)	—	10	mA
I_{PP1}	Vpp Current During Read[4]	Vcc = Max., $\overline{CE}$ = $\overline{OE}$ = V_{IL} Vpp = Vcc	—	10	μA
I_{CCSB0}	Vcc CMOS Standby Current	$\overline{CE}$ = Vcc + 0.3V (No toggling)	—	20	μA
I_{CCSB1}	Vcc TTL Standby Current	$\overline{CE}$ = V_{IH} (No toggling)	—	200	μA

Notes:
1. Vcc must be applied simultaneously or before Vpp and removed simultaneously or after Vpp. Never try to force Vpp LOW to 1V below Vcc. Manufacturer suggests to tie Vpp and Vcc together during the READ operation.
2. **Caution:** the IS27LV020 must not be removed from (or inserted into) a socket when Vcc or Vpp is applied.
3. Icc1 is tested with $\overline{OE}$ = V_{IH} to simulate open outputs.
4. Maximum active power usage is the sum of Icc and Ipp.
5. Minimum DC input voltage is –0.5V. During transitions, the inputs may undershoot to –2.0V for periods less than 10 ns. Maximum DC voltage on output pins is Vcc + 0.5V which may overshoot to Vcc + 2.0V for periods less than 10 ns.

CAPACITANCE[1,2,3]

Symbol	Parameter	Conditions	Typ.	Max.	Unit
C_{IN}	Input Capacitance	V_{IN} = 0V	8	10	pF
C_{OUT}	Output Capacitance	V_{OUT} = 0V	8	12	pF

Notes:
1. Typical values are for nominal supply voltage.
2. This parameter is only sampled, but not 100% tested.
3. Test conditions: T_A = 25°C, f = 1 MHz.

SWITCHING TEST CIRCUIT
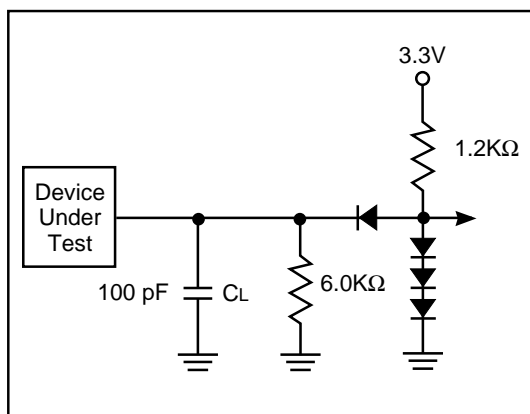
SWITCHING TEST WAVEFORM
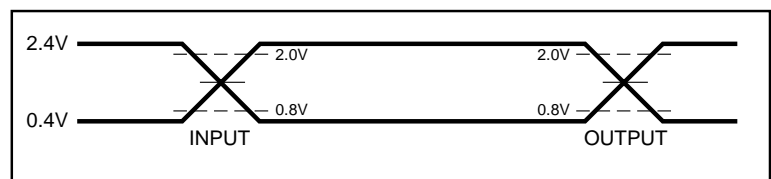
Notes:
AC Testing:
1. Inputs are driven at 2.4V for a logic "1" and 0.4V for a logic "0".
2. Input pulse rise and fall times are ≤ 20 ns.

SWITCHING CHARACTERISTICS[1,3,4] (Over Operating Range)

JEDEC Symbol	Std. Symbol	Parameter	Test Conditions	-90 Min.	-90 Max.	-12 Min.	-12 Max.	-15 Min.	-15 Max.	Unit
t_{AVQA}	t_{ACC}	Address to Output Delay	$\overline{CE} = \overline{OE} = V_{IL}$	—	90	—	120	—	150	ns
t_{ELQV}	t_{CE}	Chip Enable to Output Delay	$\overline{OE} = V_{IL}$ $C_L = C_{L1}$	—	90	—	120	—	150	ns
t_{GLQV}	t_{OE}	Output Enable to Output Delay	$\overline{CE} = V_{IL}$	—	45	—	50	—	65	ns
t_{EHOZ}, t_{GHQZ}	t_{DF}[2]	Chip Enable HIGH or Output Enable HIGH, whichever comes first, to Output Float		—	30	—	35	—	35	ns
t_{AVOX}	t_{OH}	Output Hold from Address, $\overline{CE}$ or $\overline{OE}$ whichever occured first		0	—	0	—	0	—	ns

Notes:
1. V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP}.
2. This parameter is only sampled, not 100% tested.
3. **Caution:** The IS27LV020 must not be removed from (or inserted into) a socket or board when V_{PP} or V_{CC} applied.
4. Output Load: 1 TTL gate and C_L =100 pF.
   Input Rise and Fall times: 20 ns.
   Input Pulse Levels: 0.4V to 2.4V.
   Timing Measurement Reference Level: 0.8V to 2V for inputs and outputs.

SWITCHING WAVEFORMS
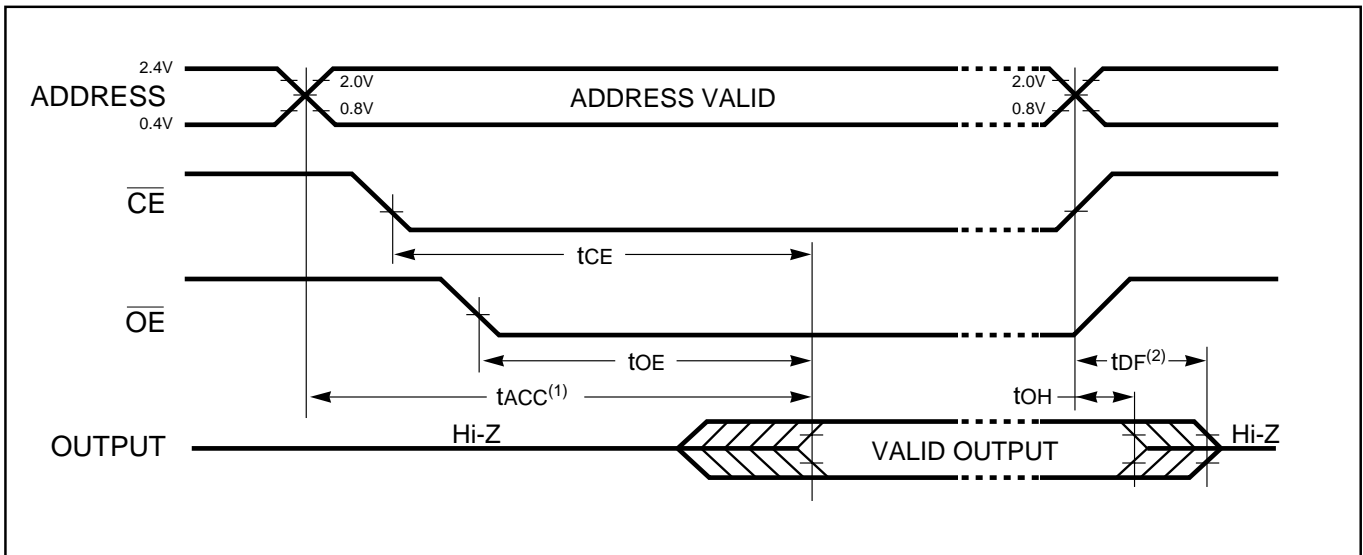
Notes:
1. $\overline{OE}$ may be delayed up to t_{ACC} – t_{OE} after the falling edge of $\overline{CE}$ without impact on t_{ACC}.
2. t_{DF} is specified from $\overline{OE}$ or $\overline{CE}$, whichever occurs first.

DC PROGRAMMING CHARACTERISTICS[1,2,3,4] (T_A = +25°C ± 5°C)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
V_{OH}	Output HIGH Voltage During Verify	I_{OH} = –400 µA	2.4	—	V
V_{OL}	Output LOW Voltage During Verify	I_{OL} = 2.1 mA	—	0.45	V
V_{IH}	Input HIGH Voltage		2.0	V_{CC} + 0.5	V
V_{IL}	Input LOW Voltage (All Inputs)		–0.3	0.8	V
V_H	A9 Auto Select Voltage		11.5	12.5	V
I_{LI}	Input Current (All Inputs)	V_{IN} = V_{IL} or V_{IH}	—	10.0	µA
I_{CC}	Vcc Supply Current (Program & Verify)		—	50	mA
I_{PP}	Vpp Supply Current	$\overline{CE}$ = V_{IL}, $\overline{OE}$ = V_{IH}	—	30	mA
V_{CC}	Supply Voltage		5.75	6.25	V
V_{PP}	Programming Voltage		12.25	12.75	V

SWITCH PROGRAMMING CHARACTERISTICS[1,2,3,4] (T_A = +25°C ± 5°C)

JEDEC Symbol	Std. Symbol	Parameter	Min.	Max.	Unit
t_{AVEL}	t_{AS}	Address Setup Time	2	—	µs
t_{DZGL}	t_{OES}	$\overline{OE}$ Setup Time	2	—	µs
t_{DVEL}	t_{DS}	Data Setup Time	2	—	µs
t_{GHAX}	t_{AH}	Address Hold Time	0	—	µs
t_{EHDX}	t_{DH}	Data Hold Time	2	—	µs
t_{GHQZ}	t_{DFP}	$\overline{OE}$ HIGH to Output Float Delay	0	130	ns
t_{VPS}	t_{VPS}	Vpp Setup Time	2	—	µs
t_{ELEH1}	t_{PW}	$\overline{PGM}$ Program Pulse Width	95	105	µs
t_{VCS}	t_{VCS}	Vcc Setup Time	2	—	µs
t_{ELPL}	t_{CES}	$\overline{CE}$ Setup Time	2	—	µs
t_{GLQV}	t_{OE}	Data Valid from $\overline{OE}$	—	150	ns

Notes:
1. Vcc must be applied simultaneously or before Vpp and removed simultaneously or after Vpp.
2. Vpp must be ≥ Vcc during the entire programming and verifying procedure.
3. When programming IS27LV020, a 0.1 µF capacitor is required across Vpp and ground to suppress spurious voltage transients which may damage the device.
4. Programming characteristics are sampled but not 100% tested at worst-case conditions.

PROGRAMMING ALGORITHM WAVEFORM[1,2]
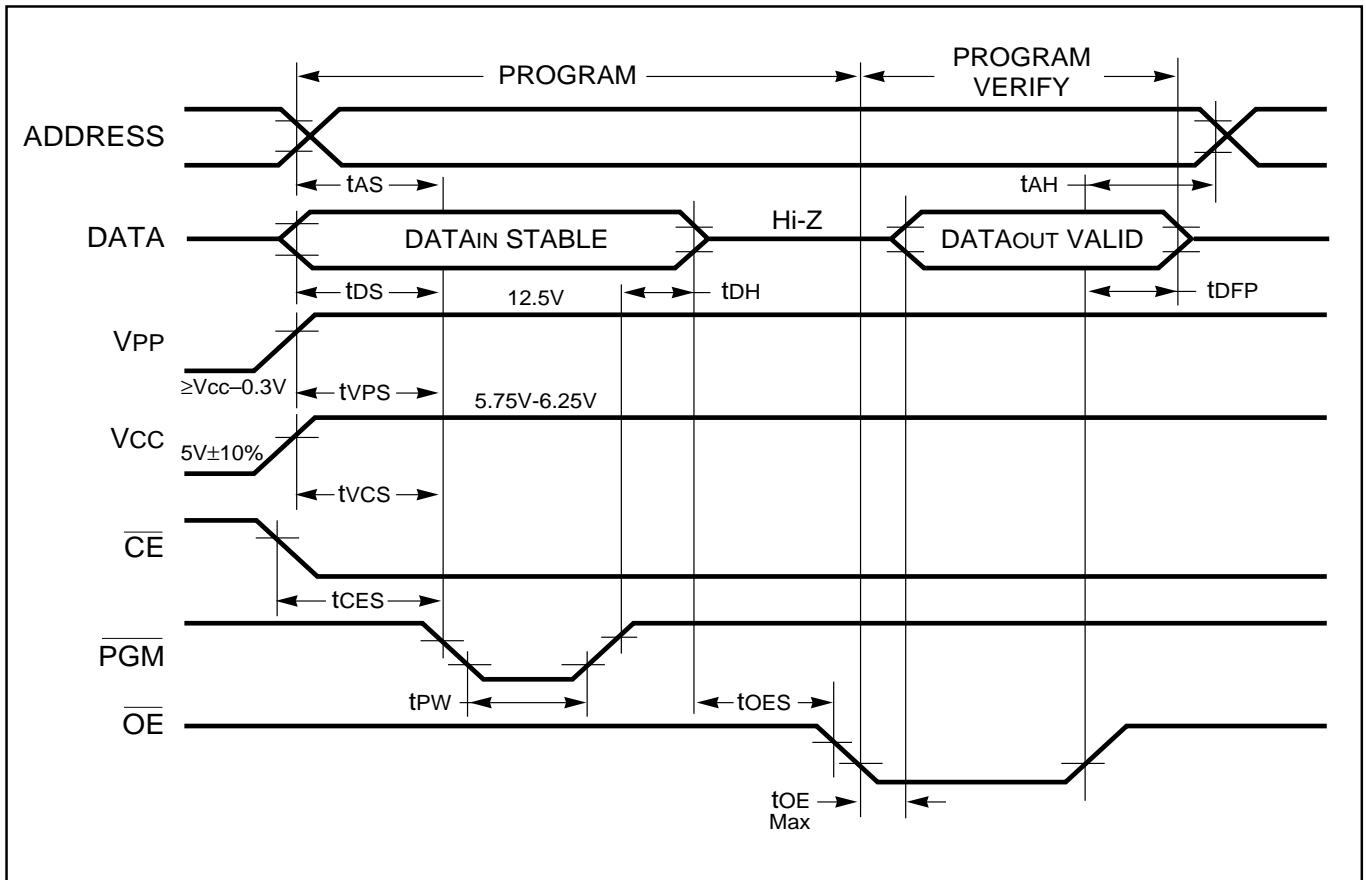
Notes:
1. The timing reference level is 0.8V for V_{IL} and 2.0V for V_{IH}.
2. t_{OE} and t_{DFP} are characteristics of the device but must be accommodated by the programmer.

PROGRAMMING FLOW CHART

```
                                    ┌──────────┐
                                    │  Start   │
                                    └────┬─────┘
                                         ▼
                              ┌──────────────────────┐
                              │ Address = First Location│
                              └──────────┬───────────┘
                                         ▼
                              ┌──────────────────────┐
                              │    Vcc = 6V          │
                              │    VPP = 12.5V       │
                              └──────────┬───────────┘
                                         ▼
                              ┌──────────────────────┐
                   ┌─────────▶│    X = 0             │
                   │          └──────────┬───────────┘
                   │                     ▼
                   │          ┌──────────────────────┐
                   │     ┌───▶│ Program One 100 μs Pulse│
                   │     │    └──────────┬───────────┘
                   │     │               ▼
                   │     │    ┌──────────────────────┐
                   │     │    │  Increment X         │
                   │     │    └──────────┬───────────┘
                   │     │               ▼
                   │     │          ◇ X = 25? ◇ ──── Yes ────┐
                   │     │               │ No               │
                   │     │               ▼                  │
                   │     └── Fail ── ◇ Verify Byte ◇        │
                   │                     │ Pass             │
                   │                     ▼                  │
                   │   ┌──────────────┐  ◇ Last Address? ◇  │
                   └───│Increment Address│◀── No            │
                       └──────────────┘     │ Yes           │
                                            ▼               │
                                 ┌──────────────────┐       │
                                 │ Vcc = VPP = 5.25V│       │
                                 └────────┬─────────┘       │
                                          ▼                 ▼
                                   ◇ Verify All ◇── Fail ─▶┌────────────┐
                                   ◇  Bytes     ◇          │Device Failed│
                                          │ Pass           └────────────┘
                                          ▼
                                 ┌──────────────┐
                                 │Device Passed │
                                 └──────────────┘
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Interactive programming Section

Verify Section

Integrated Silicon Solution, Inc.
EP019-0A
12/19/97
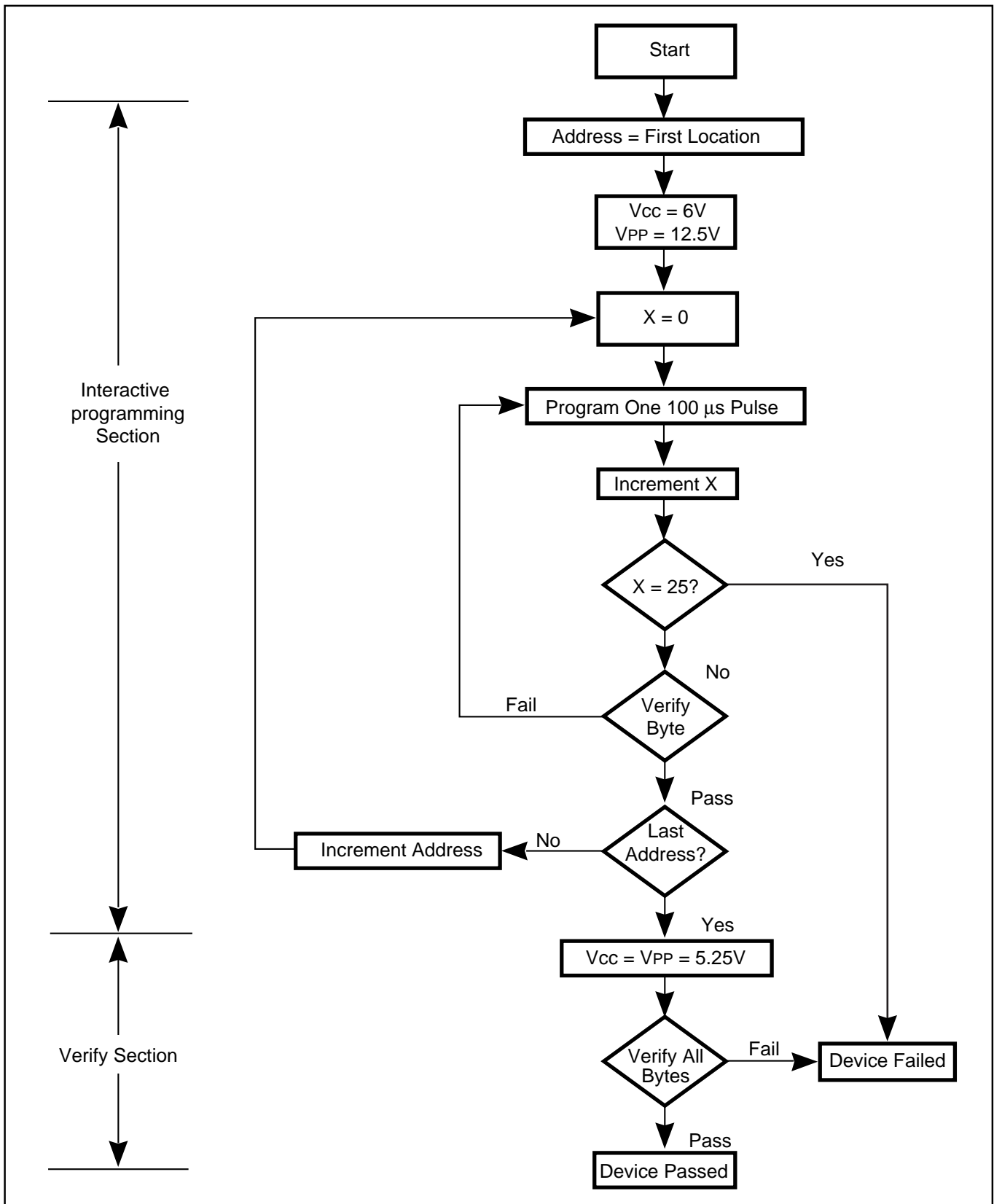
ORDERING INFORMATION

Commercial Range: 0°C to +70°C

Speed (ns)	Order Part Number	Package
90	IS27LV020-90W IS27LV020-90PL IS27LV020-90T	600-mil Plastic DIP PLCC – Plastic Leaded Chip Carrier TSOP
120	IS27LV020-12W IS27LV020-12PL IS27LV020-12T	600-mil Plastic DIP PLCC – Plastic Leaded Chip Carrier TSOP
150	IS27LV020-15W IS27LV020-15PL IS27LV020-15T	600-mil Plastic DIP PLCC – Plastic Leaded Chip Carrier TSOP

ORDERING INFORMATION

Industrial Rangle: –40°C to +85°C

Speed (ns)	Order Part Number	Package
90	IS27LV020-90PLI IS27LV020-90TI	PLCC – Plastic Leaded Chip Carrier TSOP
120	IS27LV020-12PLI IS27LV020-12TI	PLCC – Plastic Leaded Chip Carrier TSOP
150	IS27LV020-15PLI IS27LV020-15TI	PLCC – Plastic Leaded Chip Carrier TSOP

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